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Texas Instruments SN74HC00DR

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Datasheet of SN74HC00DR - IC GATE NAND 4CH 2-INP 14-SOIC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



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TEXAS INSTRUMENTS

SN54HC00, SN74HC00

SCLS181F-DECEMBER 1982-REVISED JULY 2016

# SNx4HC00 Quadruple 2-Input Positive-NAND Gates

## 1 Features

- Wide Operating Voltage Range of 2 V to 6 V
- Outputs Can Drive Up to 10 LSTTL Loads
- Low Power Consumption: I<sub>CC</sub> 20-μA (Maximum)

Product

Folder

- Typical t<sub>pd</sub>: 8 ns
- ±4-mA Output Drive at 5 V
- Low Input Current: 1 µA (Maximum)
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.

## 2 Applications

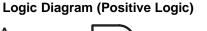
- AV Receivers
- Portable Audio Docks
- Blu-ray Players and Home Theater
- MP3 Players or Recorders
- Personal Digital Assistants (PDAs)
- Power: Telecom or Server AC/DC Supply (Single Controller: Analog and Digital)
- Solid State Drives (SSDs): Client and Enterprise
- TVs: LCD, Digital, and High-Definition (HDTV)
- Tablets: Enterprise
- Video Analytics: Server
- Wireless Headsets, Keyboards, and Mice

## 3 Description

The SN54HC00 and SN74HC00 devices contain four independent, 2-input NAND gates. They perform the Boolean function  $Y = \overline{A} \times \overline{B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

	Device Information <sup>(1)</sup>						
PART NUMBER	PACKAGE (PINS)	BODY SIZE (NOM)					
	CDIP (14)	6.92 mm × 19.94 mm					
SN54HC00	CFP (14)	6.20 mm × 9.41 mm					
	LCCC (20)	8.89 mm × 8.89 mm					
SN74HC00D	SOIC (14)	8.65 mm × 3.91 mm					
SN74HC00DB	SSOP (14)	6.20 mm × 5.30 mm					
SN74HC00N	PDIP (14)	19.30 mm × 6.35 mm					
SN74HC00NS	SOP (14)	10.30 mm × 5.30 mm					
SN74HC00PW	TSSOP (14)	5.00 mm × 4.40 mm					

(1) For all available packages, see the orderable addendum at the end of the data sheet.





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#### SN54HC00, SN74HC00

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13		hanical, Packaging, and Orderable rmation

## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from	Revision E	(August	2003) to	<b>Revision F</b>
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## Page

•	Added Applications section, Device Information table, ESD Ratings table, Typical Characteristics section, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical,	
	Packaging, and Orderable Information section	. 1
•	Added Military Disclaimer to Features list	. 1
•	Removed Ordering Information table; see POA at the end of data sheet	. 1
•	Changed values in the Thermal Information table to align with JEDEC standards	. 5
•	Deleted Operating Characteristics table: moved Cpd row to Electrical Characteristics	. 5



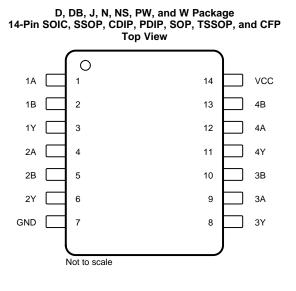
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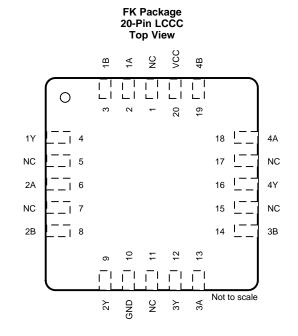
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## 5 Pin Configuration and Functions





Pin Functions
---------------

	PIN				
NAME	SOIC, SSOP, CDIP, PDIP, SOP, TSSOP, CFP	LCCC	I/O	DESCRIPTION	
1A	1	2	Ι	Gate 1 input	
1B	2	3	Ι	Gate 1 input	
1Y	3	4	0	Gate 1 output	
2A	4	6	Ι	Gate 2 input	
2B	5	8	Ι	Gate 2 input	
2Y	6	9	0	Gate 2 output	
ЗA	9	13	Ι	Gate 3 input	
3B	10	14	-	Gate 3 input	
3Y	8	12	0	Gate 3 output	
4A	12	18	Ι	Gate 4 input	
4B	13	19	Ι	Gate 4 input	
4Y	11	16	0	Gate 4 output	
GND	7	10	_	Ground pin	
NC	_	1, 5, 7, 11, 15,17		No internal connection	
V <sub>CC</sub>	14	20		Power pin	



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## 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	MAX	UNIT
Supply voltage, V <sub>CC</sub>	-0.5	7	V
Input clamp current, $I_{IK}$ (V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>CC</sub> ) <sup>(2)</sup>		±20	mA
Output clamp current, $I_{OK}$ (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> ) <sup>(2)</sup>		±20	mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$		±25	mA
Continuous current through $V_{CC}$ or GND		±50	mA
Storage temperature, T <sub>stg</sub>	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 6.2 ESD Ratings

			VALUE	UNIT
V(rep) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V	
	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	v	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	NOM	MAX	UNIT	
V <sub>CC</sub>	Supply voltage			5	6	V	
		$V_{CC} = 2 V$	1.5				
VIH	High-level input voltage	$V_{CC} = 4.5 V$	3.15			V	
		$V_{CC} = 6 V$	4.2				
V <sub>IL</sub>		$V_{CC} = 2 V$			0.5	.5	
	Low-level input voltage	$V_{CC} = 4.5 V$			1.35	V	
		V <sub>CC</sub> = 6 V			1.8		
VI	Input voltage		0		V <sub>CC</sub>	V	
Vo	Output voltage		0		$V_{CC}$	V	
		$V_{CC} = 2 V$			1000		
$\Delta t / \Delta v$	Input transition rise and fall time	$V_{CC} = 4.5 V$			500	ns	
		V <sub>CC</sub> = 6 V			400		
-	Operating free air temperature	SN54HC00	-55		125	°C	
T <sub>A</sub>	Operating free-air temperature	SN74HC00	-40		85	C	

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to Implications of Slow or Floating CMOS Inputs application report.



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## 6.4 Thermal Information

				SN74HC00			
	THERMAL METRIC <sup>(1)</sup>	D (SOIC)	DB (SSOP)	N (PDIP)	NS (SOP)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{ hetaJA}$	Junction-to-ambient thermal resistance	94.7	108.3	57.5	91	122.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	54.6	60.3	45.1	48.8	51.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	49	55.7	37.3	49.8	64.6	°C/W
ΨJT	Junction-to-top characterization parameter	21.1	25	30.3	18.4	6.6	°C/W
Ψјв	Junction-to-board characterization parameter	48.7	55.2	37.2	49.5	64	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER		TEST CONDITIONS		MIN	ТҮР	MAX	UNIT
				$V_{CC} = 2 V$	1.9	1.998		
			I <sub>OH</sub> = -20 μA	$V_{CC} = 4.5 V$	4.4	4.499		
				$V_{CC} = 6 V$	5.9	5.999		
				T <sub>A</sub> = 25°C	3.98	4.3		
V <sub>OH</sub>		$V_I = V_{IH} \text{ or } V_{IL}$	$I_{OH}$ = -4 mA, $V_{CC}$ = 4.5 V	SN54HC00	3.7			V
				SN74HC00	3.84			
				$T_A = 25^{\circ}C$	5.48	5.8		
			$I_{OH} = -5.2 \text{ mA}, V_{CC} = 6 \text{ V}$	SN54HC00	5.2			
				SN74HC00	5.34			
				$V_{CC} = 2 V$		0.002	0.1	
			I <sub>OL</sub> = 20 μA	$V_{CC} = 4.5 V$		0.001	0.1	V
				$V_{CC} = 6 V$		0.001	0.1	
			$I_{OL}$ = 4 mA, $V_{CC}$ = 4.5 V	$T_A = 25^{\circ}C$		0.17	0.26	
V <sub>OL</sub>	V	$V_{I} = V_{IH}$ or $V_{IL}$		SN54HC00			0.4	
				SN74HC00			0.33	
			$I_{OL} = 5.2 \text{ mA}, V_{CC} = 6 \text{ V}$	$T_A = 25^{\circ}C$		0.15	0.26	
				SN54HC00			0.4	
				SN74HC00			0.33	
1		$V_1 = V_{CC}$ or 0, $V_{CC} = 6 V$	$T_A = 25^{\circ}C$			±0.1	±100	nA
1		$v_{\rm I} = v_{\rm CC} \text{ or } 0, v_{\rm CC} = 0 \text{ v}$	SNx4HC00				±1000	IIA
			$T_A = 25^{\circ}C$				2	
I <sub>CC</sub>		$V_I = V_{CC} \text{ or } 0, I_O = 0,$ $V_{CC} = 6 V$	SN54HC00				40	μA
			SN74HC00				20	
Ci		$V_{CC} = 2 V \text{ to } 6 V$				3	10	pF
C <sub>pd</sub>	Power dissipation capacitance per gate	No load, T <sub>A</sub> = 25°C				20		pF



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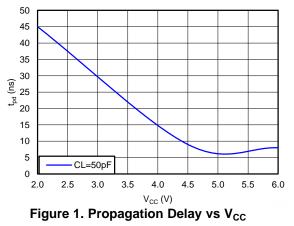
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#### 6.6 Switching Characteristics

over recommended operating free-air temperature range, CL= 50 pF, see Figure 2 (unless otherwise noted)

PARAMETER	TEST C	CONDITIONS		MIN	TYP	MAX	UNIT
			$T_A = 25^{\circ}C$		45	90	
		$V_{CC} = 2 V$	SN54HC00			135	
			SN74HC00			115	
			$T_A = 25^{\circ}C$		9	18	
t <sub>pd</sub>	From A or B (input) to Y (output)	$V_{CC} = 4.5 V$	SN54HC00			27	ns
			SN74HC00			23	
			T <sub>A</sub> = 25°C		8	15	
		$V_{CC} = 6 V$	SN54HC00			23	
			SN74HC00			20	
			T <sub>A</sub> = 25°C		38	75	
		$V_{CC} = 2 V$	SN54HC00			110	
			SN74HC00			95	
			T <sub>A</sub> = 25°C		8	15	
t <sub>t</sub>	To Y (output)	$V_{CC} = 4.5 V$	SN54HC00			22	ns
			SN74HC00			19	
			T <sub>A</sub> = 25°C		6	13	
		$V_{CC} = 6 V$	SN54HC00			19	
			SN74HC00			16	

## 6.7 Typical Characteristics

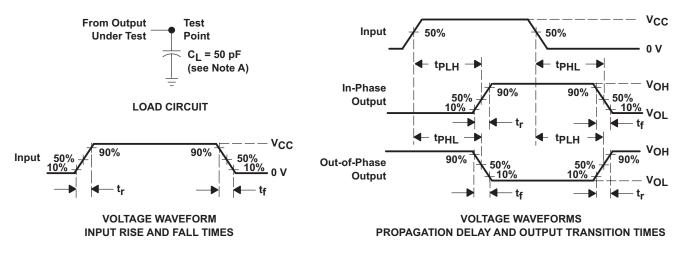




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## 7 Parameter Measurement Information



- NOTES: A. CL includes probe and test-fixture capacitance.
  - B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>r</sub> = 6 ns, t<sub>f</sub> = 6 ns.
  - C. The outputs are measured one at a time with one input transition per measurement.
  - D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

#### Figure 2. Load Circuit and Voltage Waveforms



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## 8 Detailed Description

#### 8.1 Overview

The SNx4HC00 devices perform the NAND Boolean function  $Y = \overline{A} \times \overline{B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic. The devices have a wide operating range of V<sub>CC</sub> from 2 V to 6 V.

## 8.2 Functional Block Diagram



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#### 8.3 Feature Description

The SNx4HC00 devices have a wide operating voltage range that operates from 2 V to 6 V. They allow inputs and outputs up to  $V_{CC}$ . The devices can drive outputs at 4 mA at 5-V  $V_{CC}$ .

#### 8.4 Device Functional Modes

Table 1 lists the functional modes for the SNx4HC00.

Table	1.	Function	Table
-------	----	----------	-------

INP	UTS	OUTPUT				
Α	В	Y				
Н	Н	L				
L	Х	Н				
Х	L	Н				



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## 9 Application and Implementation

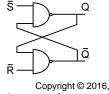
#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 9.1 Application Information

The SNx4HC00 is a low-power, wide-operating-voltage NAND gate. This device can drive up to 10 LSTTL loads and can drive 4-mA outputs at 5-V  $V_{CC}$ .

## 9.2 Typical Application



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## Figure 3. Typical NAND Gate Application and Supply Voltage

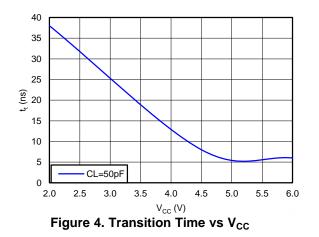
#### 9.2.1 Design Requirements

The SNx4HC00 devices use CMOS technology and have balanced output drive. Take care to avoid bus contention because it drives currents that would exceed maximum limits. The high drive also creates fast edges into light loads. Routing and load conditions must be considered to prevent ringing.

## 9.2.2 Detailed Design Procedure

- Recommended input conditions:
- Specified high and low levels. See V<sub>IH</sub> and V<sub>IL</sub> in *Recommended Operating Conditions*.
- Recommended output conditions:
  - Load currents must not exceed 25 mA per output and 50 mA total for the part.
  - Outputs must not be pulled above V<sub>CC</sub>.

## 9.2.3 Application Curve



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## **10** Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in *Recommended Operating Conditions*.

Each V<sub>CC</sub> pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends a 0.1- $\mu$ F bypass capacitor; if there are multiple V<sub>CC</sub> pins, then TI recommends 0.01- $\mu$ F or 0.022- $\mu$ F bypass capacitors for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1  $\mu$ F and a 1  $\mu$ F are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

## 11 Layout

## 11.1 Layout Guidelines

When using multiple bit logic devices inputs must never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input and gate are used or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 5 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they are tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver.

#### 11.2 Layout Example

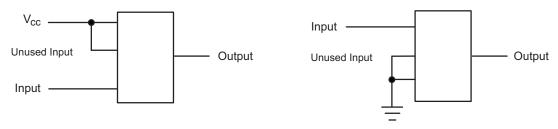


Figure 5. Layout Diagram



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## **12** Device and Documentation Support

## **12.1** Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following: Implications of Slow or Floating CMOS Inputs (SCBA004)

## 12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

#### Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54HC00	Click here	Click here	Click here	Click here	Click here
SN74HC00	Click here	Click here	Click here	Click here	Click here

## 12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

## 12.5 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8403701VCA	ACTIVE	CDIP	J	14	1	TBD	(6) A42	N / A for Pkg Type	-55 to 125	(4/5) 5962-8403701VC A SNV54HC00J	Samples
5962-8403701VDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8403701VD A SNV54HC00W	Samples
84037012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	84037012A SNJ54HC 00FK	Samples
8403701CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8403701CA SNJ54HC00J	Samples
8403701DA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8403701DA SNJ54HC00W	Samples
JM38510/65001B2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	JM38510/ 65001B2A	Samples
JM38510/65001BCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65001BCA	Samples
JM38510/65001BDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65001BDA	Samples
M38510/65001B2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	JM38510/ 65001B2A	Samples
M38510/65001BCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65001BCA	Samples
M38510/65001BDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65001BDA	Samples
SN54HC00J	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN54HC00J	Samples
SN74HC00D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Samples
SN74HC00DBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Samples
SN74HC00DE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Samples
SN74HC00DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Samples



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sam
SN74HC00DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 85	HC00	Sam
SN74HC00DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	San
SN74HC00DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sar
SN74HC00DT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sai
SN74HC00DTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00DTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00N	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU   CU SN	N / A for Pkg Type	-40 to 85	SN74HC00N	Sa
SN74HC00N3	OBSOLETE	PDIP	Ν	14		TBD	Call TI	Call TI	-40 to 85		
SN74HC00NE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC00N	Sa
SN74HC00NSLE	OBSOLETE	SO	NS	14		TBD	Call TI	Call TI	-40 to 85		
SN74HC00NSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00PWLE	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		
SN74HC00PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00PWRE4	ACTIVE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		Sa
SN74HC00PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SN74HC00PWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC00	Sa
SNJ54HC00FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	84037012A SNJ54HC 00FK	Sa



15-Jul-2016

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54HC00J	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8403701CA SNJ54HC00J	Samples
SNJ54HC00W	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8403701DA SNJ54HC00W	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tis terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(6) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "--" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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15-Jul-2016

#### OTHER QUALIFIED VERSIONS OF SN54HC00, SN54HC00-SP, SN74HC00 :

• Catalog: SN74HC00, SN54HC00

- Automotive: SN74HC00-Q1, SN74HC00-Q1
- Military: SN54HC00
- Space: SN54HC00-SP

NOTE: Qualified Version Definitions:

- ${\scriptstyle \bullet}$  Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

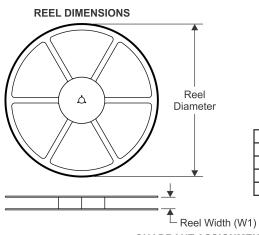


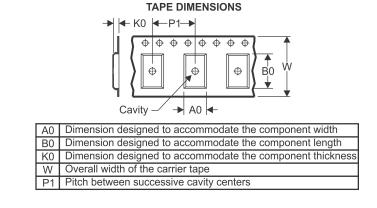


# PACKAGE MATERIALS INFORMATION

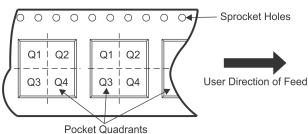
10-Mar-2016

## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC00DBR	SSOP	DB	14	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74HC00DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC00DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC00DR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.3	8.0	16.0	Q1
SN74HC00DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC00DT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC00PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC00PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC00PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC00PWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

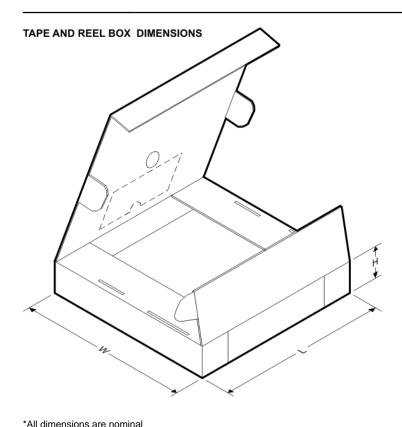


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# PACKAGE MATERIALS INFORMATION

10-Mar-2016

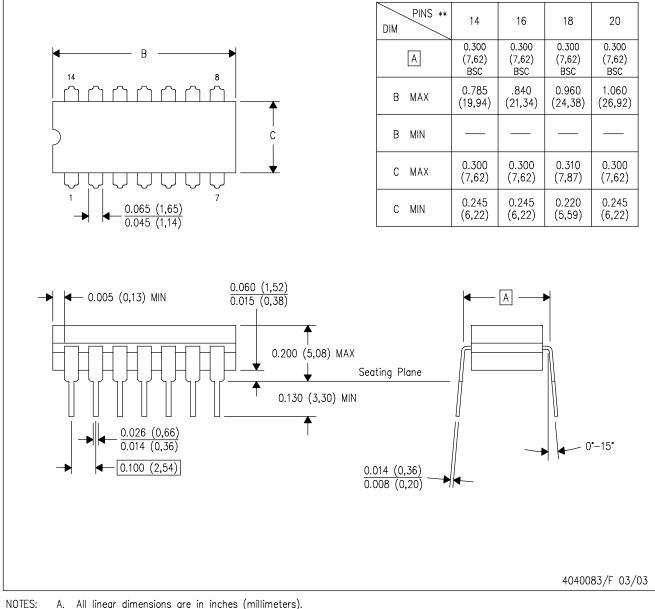


All dimensions are nominal						1	
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC00DBR	SSOP	DB	14	2000	367.0	367.0	38.0
SN74HC00DR	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC00DR	SOIC	D	14	2500	333.2	345.9	28.6
SN74HC00DR	SOIC	D	14	2500	364.0	364.0	27.0
SN74HC00DRG4	SOIC	D	14	2500	333.2	345.9	28.6
SN74HC00DT	SOIC	D	14	250	367.0	367.0	38.0
SN74HC00PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74HC00PWR	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC00PWRG4	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC00PWT	TSSOP	PW	14	250	367.0	367.0	35.0



## J (R-GDIP-T\*\*) 14 LEADS SHOWN

# CERAMIC DUAL IN-LINE PACKAGE



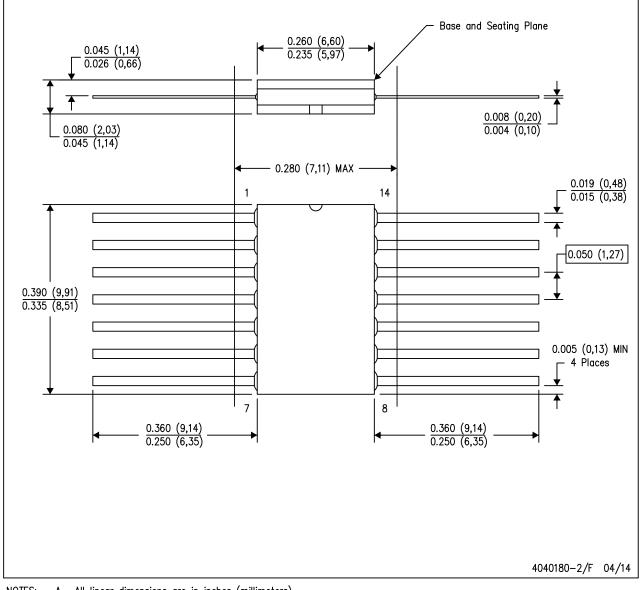
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package is hermetically sealed with a ceramic lid using glass frit.
  - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
  - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



# **MECHANICAL DATA**

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



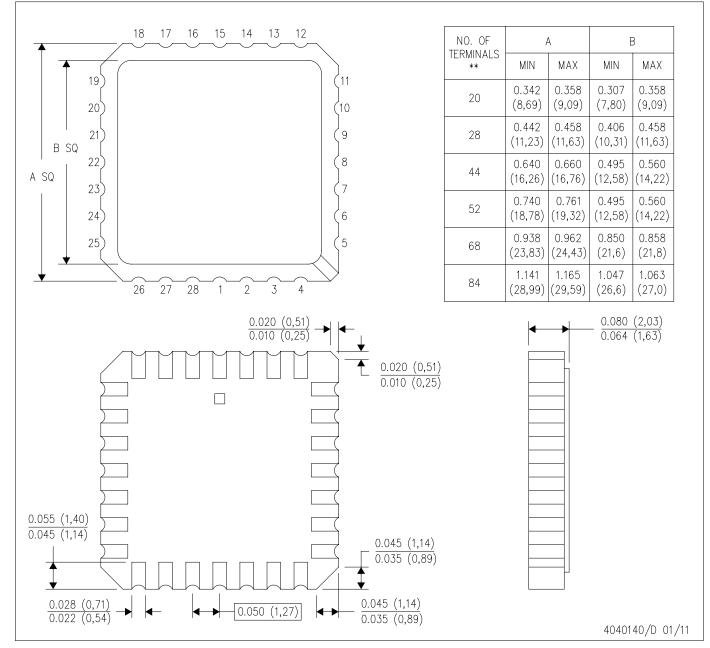
NOTES:

- All linear dimensions are in inches (millimeters). Α.
- Β. This drawing is subject to change without notice. This package can be hermetically sealed with a ceramic lid using glass frit. C.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14





FK (S-CQCC-N\*\*) 28 terminal shown LEADLESS CERAMIC CHIP CARRIER



NOTES:

A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.

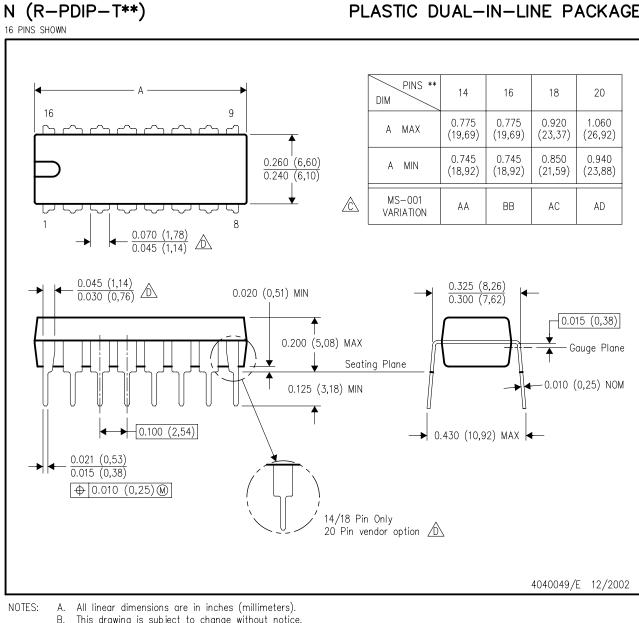
C. This package can be hermetically sealed with a metal lid.

D. Falls within JEDEC MS-004





## **MECHANICAL DATA**



PLASTIC DUAL-IN-LINE PACKAGE

- This drawing is subject to change without notice.
- 🖄 Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

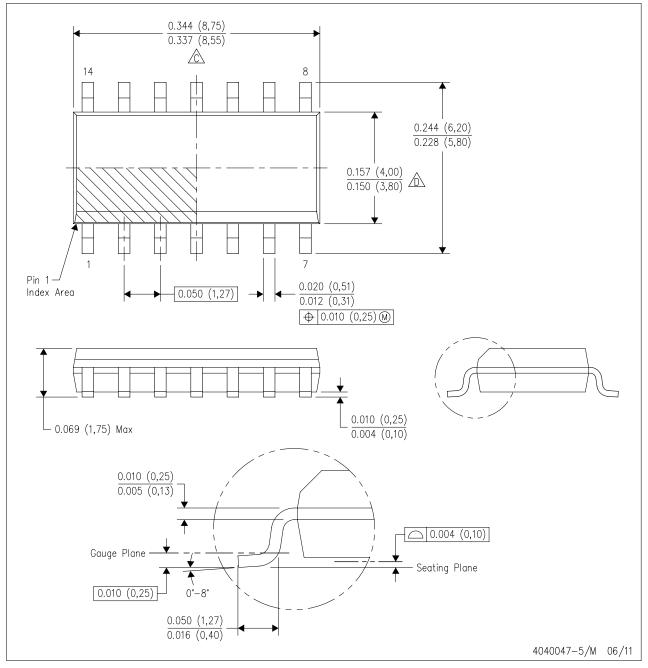




# **MECHANICAL DATA**

# D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

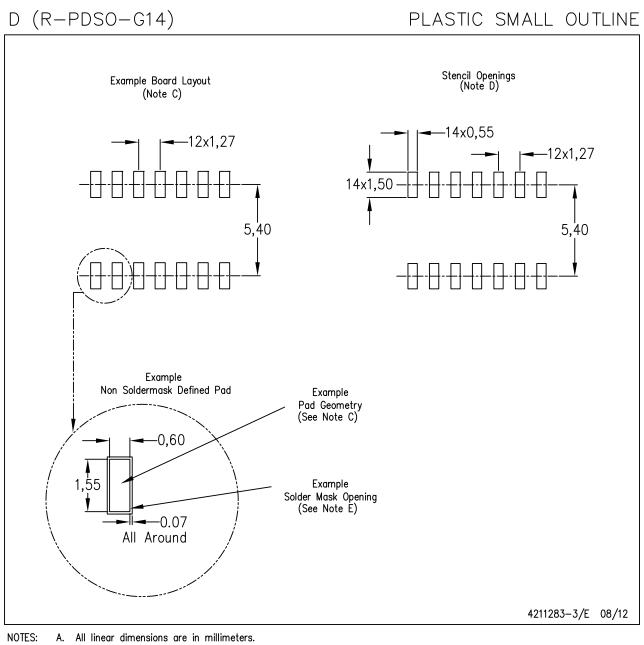
A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





# LAND PATTERN DATA



- This drawing is subject to change without notice. B.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

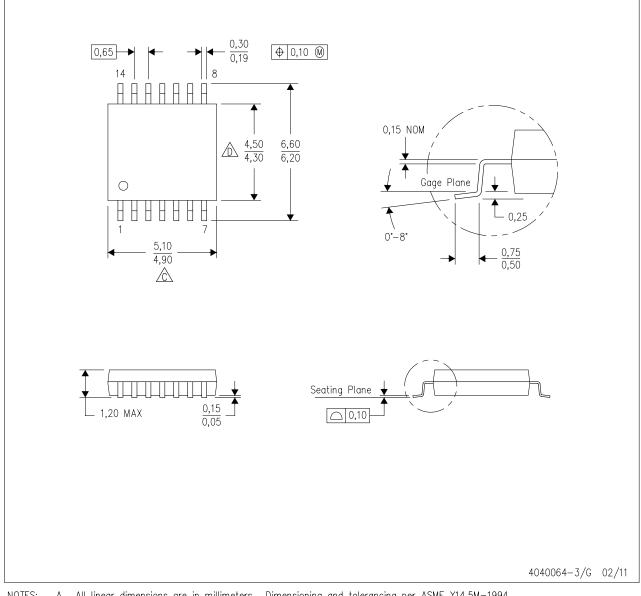




# **MECHANICAL DATA**

# PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. Ŗ. This drawing is subject to change without notice.  $\triangle$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall

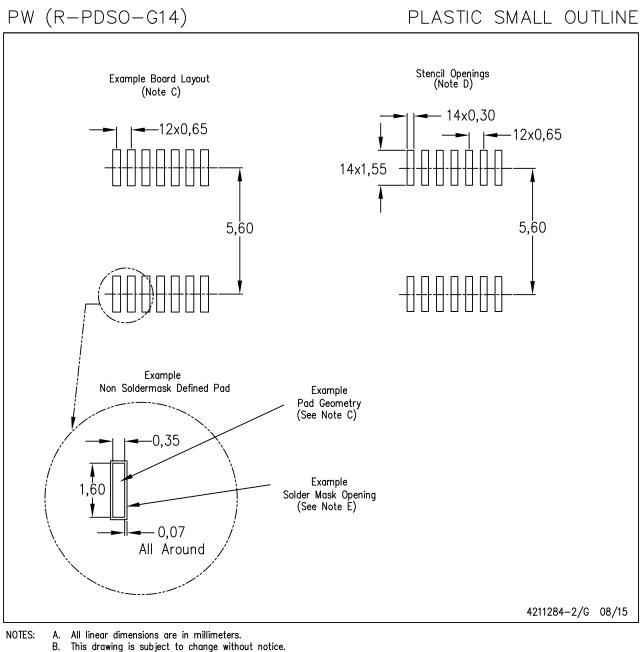
not exceed 0,15 each side. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





# LAND PATTERN DATA



- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

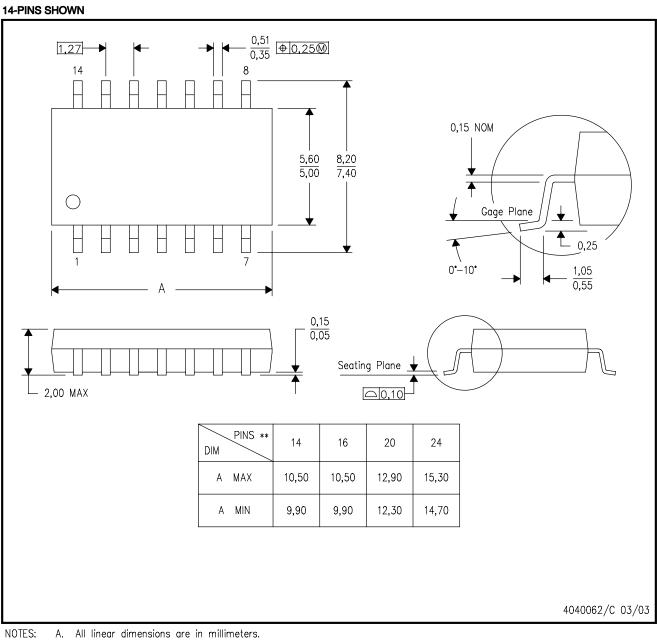




NS (R-PDSO-G\*\*)

## MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE



B. This drawing is subject to change without notice.

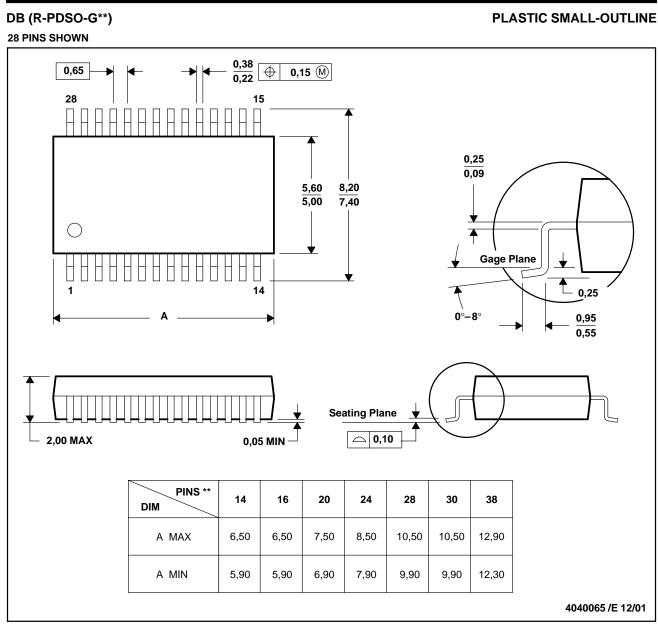
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.





## **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150





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